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	AG	de No: 138AQ  JAWAHARLAL NEHRU TECHNOLOGICAL UNIVERSITY HYDERABAD  B. Tech IV Year II Semester Examinations, December - 2020  ANALOG CMOS IC DESIGN  (Electronics and Communication Engineering)  Max.Marks:75  Answer any Five Questions  All Questions Carry Equal Marks	Ą
	AĞ	What are the parasitic capacitances of MOSFET and derive a small signal model that have an impact on the electrical behavior of the circuit and influence its electrical properties. Give a graphical overview of different operations involved in a typical photolithographic process.	A
	2.	Derive an expression for $g_m$ of an N-channel MOSFET operating in linear and saturation regions. Explain the significance of each parameter of it. [15]	
	<u>A</u> 3.	What is Current Mirror? Explain the general properties of current mirrors with block [15]	A
	4.	Analysis and design the sub-block of MOS diode using floating resistor realization. [15]	
	△ (	What is the importance of cascode amplifier? Obtain the expression for voltage gain and output impedance.  [15]  Explain how constant gain and stability is achieved in wide swing differential amplifier.  [15]	A
	7. A ( 8.a) b)	Describe the operation of two-stage op-amps with balanced and unbalanced outputs and explain the methods by which the output impedance can be increased without adding more cascade devices.  Explain about the discrete time comparator with a built-in threshold.  Explain about single-stage dominant pole comparator.  [8+7]	A
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